

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
1	BRS	L1	5	(gate near10 film) near5 (high near dielectric) near10 (substrate) near15 (laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 17:25	
2	BRS	L2	133	(high near dielectric) near10 (substrate) near15 (laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 17:32	
3	BRS	L3	183	(high near dielectric) near10 (substrate) near55 (light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 17:33	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
4	BRS	L4	366	((high near dielectric) near10 (substrate)) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3))	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/23 17:34	
5	BRS	L5	20	(gate) near15 ((high near dielectric) near10 (substrate)) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3))	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/23 17:35	
6	BRS	L6	20	((gate) near15 ((high near dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3))	USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/23 17:35	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
7	BRS	L7	1	((gate) near15 ((high-dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3))	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 17:36	
8	BRS	L8	726	((gate) near15 ((dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3))	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 17:36	
9	BRS	L9	80	((gate) near15 ((dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 17:36	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
10	BRS	L10	12	((gate) near15 ((dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3) near35 (conduct\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 17:46	
11	BRS	L11	122	((gate) near15 ((dielectric) near10 (substrate))) and ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3) near35 (conduct\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:03	
12	BRS	L12	12	((dielectric) near10 (substrate)) and ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3) near35 (conduct\$3) near35 (capacitor)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:04	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
13	BRS	L13	379	((dielectric) near10 (substrate)) and ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (conduct\$3) near35 (capacitor)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:10	
14	BRS	L14	4	6747748.pn. or 6632729.pn.	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:22	
15	BRS	L15	2326	capacitor near insulating near film	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:30	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
16	BRS	L16	617	(capacitor near insulating near film) near25 (substrate)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:24	
17	BRS	L17	29	(high near dielectric) near25 (capacitor near insulating near film) near25 (substrate)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:23	
18	BRS	L18	2	(high near dielectric) near25 (capacitor near insulating near film) near25 (dop\$4) near25 (substrate)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:23	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
19	BRS	L19	14	(capacitor near insulating near film) near25 (substrate) near35 (dop\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:24	
20	BRS	L20	2	(capacitor near insulating near film) near25 (dopa\$4)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:30	
21	BRS	L21	83	(capacitor near insulating near film) near25 (dop\$4)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:30	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
22	BRS	L22	10	(dielectric) near15 (capacitor near insulating near film) near25 (dop\$4)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:32	
23	BRS	L23	11	(dielectric) near15 (capacitor near insulating near film) near25 (dop\$4 or implant\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:33	
24	BRS	L24	94	(capacitor near insulating near film) near25 (dop\$4 or implant\$3)	USPAT ; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB	2004/10/2 3 18:33	